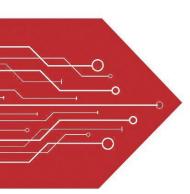
# MSKSEMI















**ESD** 

**TVS** 

**TSS** 

MOV

**GDT** 

**PLED** 

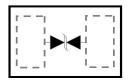
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### **PIN CONFIGURATION**





SOD-882

### **Feature**

100W peak pulse power per line ( $t_P = 8/20\mu s$ )

Replacement for MLV(0402)

Bidirectional configurations

Response time is typically < 1ns

Low clamping voltage

RoHS compliant

Transient protection for data lines to IEC61000-

4-2(ESD) ±15KV(air), ±12KV(contact);

IEC61000-4-4 (EFT) 40A (5/50ns)

### **Mechanical Characteristics**

Mounting position: Any

Qualified max reflow temperature:260°C

Device meets MSL 1 requirements

# Electrical characteristics per line@25℃ (unless otherwisespecified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V <sub>RWM</sub>				5	V
Breakdown Voltage	V <sub>BR</sub>	It = 1mA	5.6		8.5	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 5V T=25°C			1.0	μΑ
Maximum Reverse Peak Pulse Current	I <sub>PP</sub>			5.5		Α
Clamping Voltage	Vc	I <sub>PP</sub> =1A			10	V
Clamping Voltage	Vc	I <sub>PP</sub> =3A			15	V
Clamping Voltage	Vc	I <sub>PP</sub> =5A			21	V
Junction Capacitance	Cj	V <sub>R</sub> =0V f = 1MHz		0.9		pF

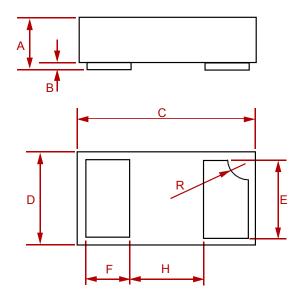
## Absolute maximum rating@25℃

Rating	Symbol	Value	Units
Peak Pulse Power (t <sub>p</sub> =8/20μs)	$P_{pp}$	100	W
Peak Pulse Current (tp=8/20µs)	I <sub>pp</sub>	5	Α
Operating Temperature	TJ	-55 to 150	°C
Storage Temperature	T <sub>STG</sub>	-55 to 150	℃



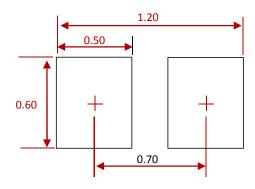
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## **PACKAGE MECHANICAL DATA**



Direc	Inches		Millimeters		
Dim	MIN	MAX	MIN	MAX	
Α	0.0125	0.02	0.32	0.52	
В	0.000	0.002	0.00	0.05	
С	0.037	0.043	0.95	1.080	
D	0.022	0.027	0.55	0.680	
E	0.016	0.024	0.40	0.60	
F	0.008	0.012	0.20	0.30	
Н	0.015Typ.		0.40Тур.		
R	0.001	0.005	0.05	0.15	

# **Suggested Pad Layout**



### NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

## **REEL SPECIFICATION**

P/N	PKG	QTY
ESD5V0X1BL-MS	SOD-882	10000



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